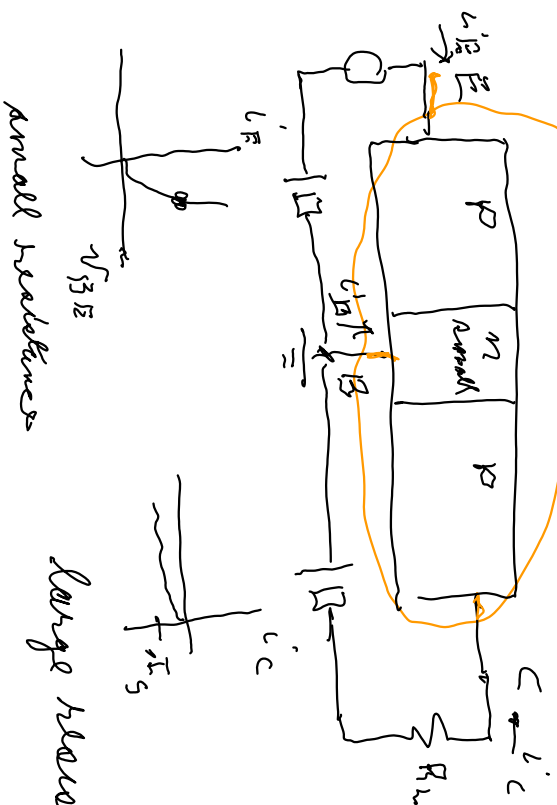


BJT = bipolar junction transistor

transfers resistance

Phasors



small holes

large holes

$$\beta \triangleq \frac{\alpha}{1-\alpha}$$

very large  $\approx h_{FE}$

$$i_C = \frac{\alpha}{1-\alpha} \cdot i_B = -\alpha i_E$$

$$i_E = \frac{1}{1-\alpha} \cdot i_B$$

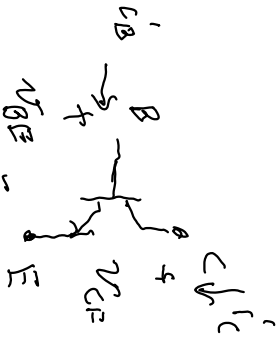
transfers resistance

$$i_C = -(\alpha i_E) \quad \alpha \approx 0.999 \quad (1)$$

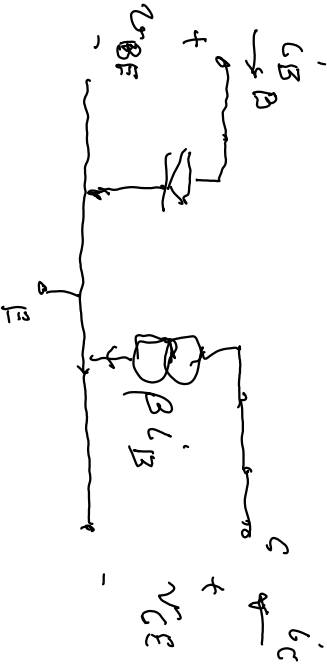
$$i_B + i_C + i_E = 0 \quad R < L \quad (2)$$

$$i_E = -i_B - i_C \quad (2a)$$

$$i_C = -\alpha(-i_B - i_C) \quad (3)$$

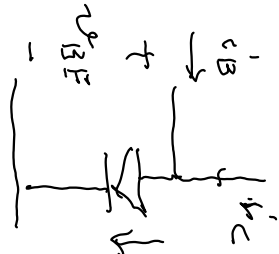


\$\Rightarrow\$



Chapter 7

Q) emitter



$$I_C = I_S \left( e^{V_{BE}/V_T} - 1 \right) \approx I_S e^{V_{BE}/V_T}$$

\$I\_S\$ = reverse saturation current

$$I_B = \beta \cdot I_C = \frac{\alpha}{\beta} I_S e^{V_{BE}/V_T} \quad \text{Kortal}$$

Reverse saturation current

derive

$$\begin{bmatrix} i_b \\ i_c \end{bmatrix} = i'$$

$$\begin{bmatrix} v_{bQ} \\ v_{cQ} \end{bmatrix} = v'$$

$$i' = Y v'$$

$$\begin{bmatrix} i_b \\ i_c \end{bmatrix} = Y_{21} \begin{bmatrix} v_{bQ} \\ v_{cQ} \end{bmatrix}$$

$$\begin{bmatrix} v_{bQ} \\ v_{cQ} \end{bmatrix}$$

$$y_{21} = \frac{\partial i_c}{\partial v_{bQ}} \Big|_Q$$

$$= \frac{\partial i_c}{\partial i_B} \cdot \frac{\partial i_B}{\partial i_E} \cdot \frac{\partial i_E}{\partial v_{BE}} \Big|_Q$$

$$= \beta(-1-\alpha) \cdot \left( -\frac{\partial I_{SE}}{\partial v_{BE}} \right)$$

$$= \frac{\alpha \cdot I_{SE}}{V_T} \approx \frac{I_C}{V_T} = \frac{\partial i_c}{\partial v_{BE}} = g_m$$

$$\underbrace{\frac{I_{SE}}{V_T}}_{\approx I_{BE}/V_T}$$

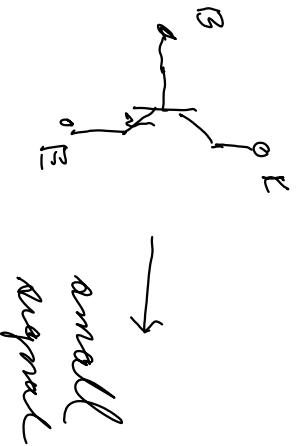
Q The B-C are a diode

$$\frac{\partial i_B}{\partial v_{BE}} = \frac{\partial i_B}{\partial i_C} \cdot \frac{\partial i_C}{\partial v_{BE}} = \frac{1}{\beta} \cdot g_m = g_{11} = g_m$$

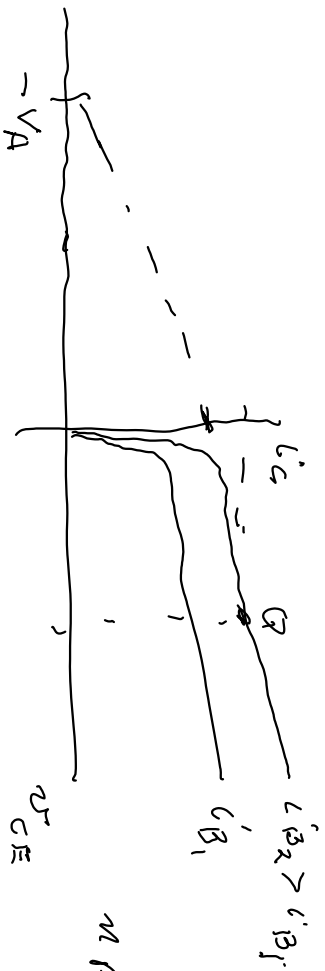
$$Y = \begin{bmatrix} g_{\pi} & 0 \\ g_m & g_o \end{bmatrix}$$

$$y_{22} = \frac{\partial i_c}{\partial v_{cE}} \approx \frac{I_C}{|V_A|} = g_o$$

$$v_B = I_B R$$

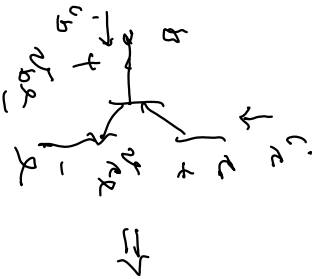


→ small signal equivalent



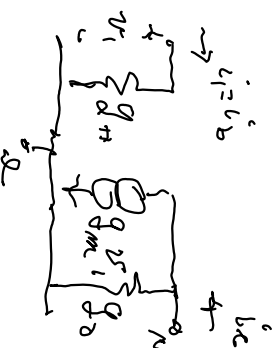
MCM circuit

$$\text{we assume } \frac{\partial i_B}{\partial v_{cE}} \approx 0 = g_{i2}$$



⇒

$$Y = \begin{bmatrix} g_{\pi} & 0 \\ g_m & g_o \end{bmatrix} = \begin{bmatrix} \frac{I_C}{\partial v_B} & 0 \\ \frac{\partial I_C}{\partial v_B} & \frac{I_C}{V_A} \end{bmatrix}$$

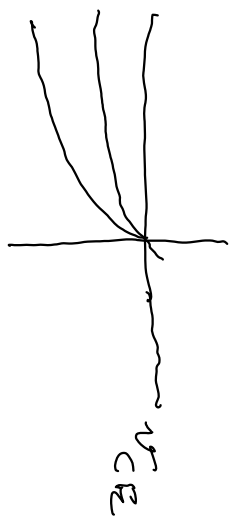
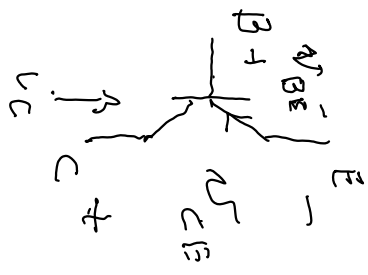


$V_A = \text{Early voltage}$   
not always

ideally if  $\beta \rightarrow \infty, V_A \rightarrow \infty$

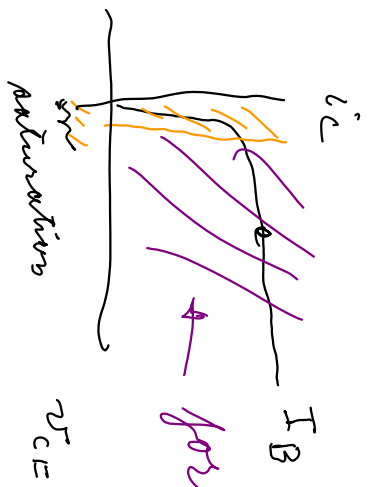
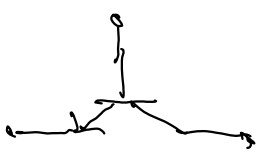
$$g_m = \begin{bmatrix} 0 & 0 \\ g_m & 0 \end{bmatrix}$$

$$\Rightarrow A_v = \frac{v_{out}}{v_{in}} = \frac{v_{ce}}{v_{be}} = -g_m R_L$$

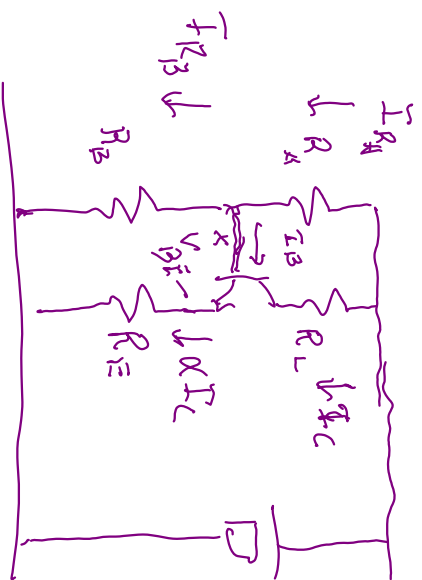


$$g_m = \frac{I_C}{V_T}, \quad g_{\pi} = \frac{g_m}{\beta}, \quad g_o = \frac{I_C}{V_A}$$

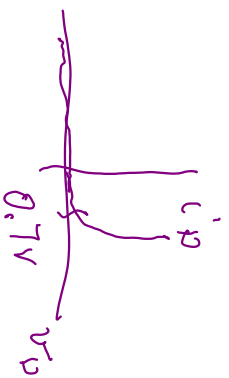
to get Q point:



forward active



need  $V_{BE}$



$R_E$  needed to keep  $I_C$  independent of temperature changes

assume  $V_{BE} = 0.7$

